SONY

SLD402S

20W Array Laser Diode

Preliminary

Description

The SLD402S is a high power laser diode with an array structure, which achieves 20W high power.

Features

- High power
 Recommended optical power output: Po = 20W
- Array structure
- Open package

Applications

Sold state laser excitation

Structure

GaAlAs quantum well structure laser diode

Operating Lifetime

MTTF 10,000H (effective value) at Po = 20W, Tc = 25°C

Absolute Maximum Ratings (Tc = 25°C)

Optical power outputPoReverse voltageVRLDV

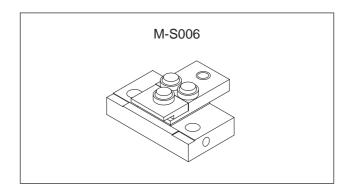
Warranty

This warranty period shall be 90 days after receipt of the product or 1,000 hours operation time whichever is shorter.

Sony Quality Assurance Department shall analyze any product that fails during said warranty period, and if the analysis results show that the product failed due to material or manufacturing defects on the part of Sony, the product shall be replaced free of charge.

Laser diodes naturally have differing lifetimes which follow a Weibull distribution.

Special warranties are also available.



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Optical and Electrical Characteristics

 $(Tc = 25^{\circ}C)$

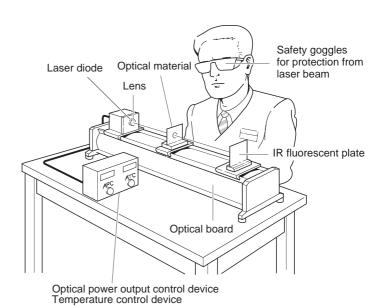
Item		Symbol	Conditions	Min.	Тур.	Max.	Unit
Threshold current		lth			6	15	А
Operating current		lop	Po = 20W		25	30	А
Operating voltage		Vop	Po = 20W		1.9	3.0	V
Wavelength		λΡ	Po = 20W	790		840	nm
Radiation angle	Perpendicular	θΤ	Po = 20W		33	40	degree
	Parallel	θ//	Po = 20W		8	15	degree
Positional accuracy	Position	ΔΧ, ΔΥ				±300	μm
	Angle	Δφ⊥	Po = 20W			±5	degree
		Δφ//				±4	degree
Differential efficiency		ηD	Po = 20W	0.5	1.0	1.5	W/A

Handling Precautions

Eye protection against laser beams

The optical output of laser diodes ranges from several mW to 3W. However the optical power density of the laser beam at the diode chip reaches 1MW/cm². Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

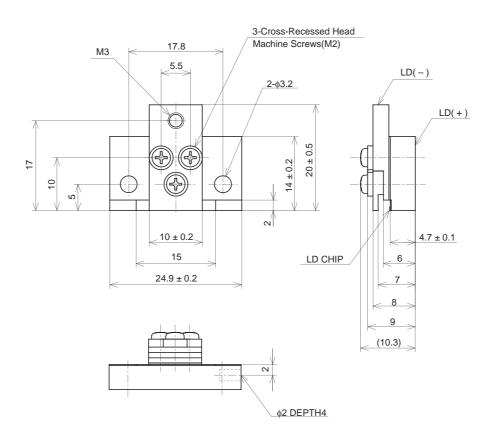
In addition, the laser diode array of this product is not protected by window glass or other covering (open package product), so special care is necessary when handling.



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Package Outline Unit: mm

M-S006



SONY CODE	M-S006			
EIAJ CODE				
JEDEC CODE				

PACKAGE WEIGHT	18.36g